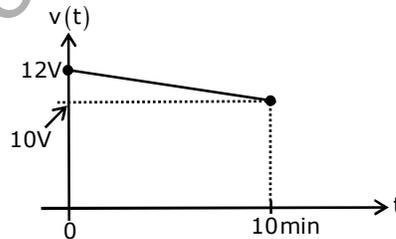


**Q. No. 1 – 20 Carry One Mark Each**

1. The order of the differential equation  $\frac{d^2y}{dt^2} + \left(\frac{dy}{dt}\right)^3 + y^4 = e^{-t}$  is  
(A) 1 (B) 2 (C) 3 (D) 4
2. The Fourier series of a real periodic function has only  
P. Cosine terms if it is even  
Q. Sine terms if it is even  
R. Cosine terms if it is odd  
S. Sine terms if it is odd  
Which of the above statements are correct?  
(A) P and S (B) P and R (C) Q and S (D) Q and R
3. A function is given  $f(t) = \sin^2 t + \cos 2t$ . Which of the following is true?  
(A)  $f$  has frequency components at 0 and  $1/2\pi$  Hz  
(B)  $f$  has frequency components at 0 and  $1/\pi$  Hz  
(C)  $f$  has frequency components at  $1/2\pi$  and  $1/\pi$  Hz  
(D)  $f$  has frequency components at 0,  $1/2\pi$  and  $1/\pi$  Hz

4. A fully charged mobile phone with a 12V battery is good for a 10minute talk-time. Assume that, during the talk-time, the battery delivers a constant current of 2A and its voltage drops linearly from 12 V to 10V as shown in the figure. How much energy does the battery deliver during this talk-time?



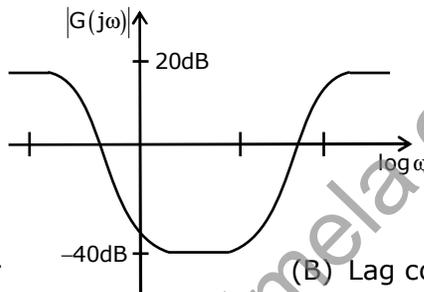
- (A) 220J (B) 12kJ (C) 13.2kJ (D) 14.4kJ
5. In an n-type silicon crystal at room temperature, which of the following can have a concentration of  $4 \times 10^{19} \text{cm}^{-3}$  ?  
(A) Silicon atoms (B) Holes  
(C) Dopant atoms (D) Valence electrons
6. The full form of the abbreviations TTL and CMOS in reference to logic families are  
(A) Triple Transistor Logic and Chip Metal Oxide Semiconductor  
(B) Tristate Transistor Logic and Chip Metal Oxide Semiconductor

- (C) Transistor Transistor Logic and Complementary Metal Oxide Semiconductor  
 (D) Tristate Transistor Logic and Complementary Metal Oxide Silicon

7. The ROC of Z-transform of the discrete time sequence  $x(n) = \left(\frac{1}{3}\right)^n u(n) - \left(\frac{1}{2}\right)^n u(-n-1)$  is

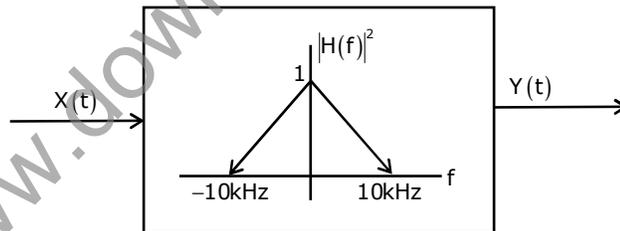
- (A)  $\frac{1}{3} < |z| < \frac{1}{2}$       (B)  $|z| > \frac{1}{2}$       (C)  $|z| < \frac{1}{3}$       (D)  $2 < |z| < 3$

8. The magnitude plot of a rational transfer function  $G(s)$  with real coefficients is shown below. When of the following compensators has such a magnitude plot?



- (A) Lead compensator      (B) Lag compensator  
 (C) PID compensator      (D) Lead-lag compensator

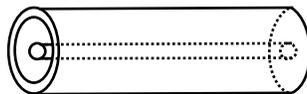
9. A white noise process  $X(t)$  with two-sided power spectral density  $1 \times 10^{-10}$  W/Hz is input to a filter whose magnitude squared response is shown below



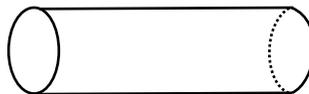
The power of the output process  $Y(t)$  is given by

- (A)  $5 \times 10^{-7}$  W      (B)  $1 \times 10^{-6}$  W      (C)  $2 \times 10^{-6}$  W      (D)  $1 \times 10^{-5}$  W

10. Which of the following statements is true regarding the fundamental mode of the metallic waveguides shown?



P. Coaxial



Q. Cylindrical



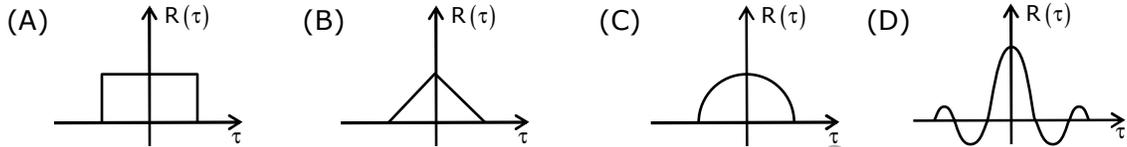
R: Rectangular

- (A) Only P has no cutoff-frequency      (B) Only Q has no cutoff-frequency  
 (C) Only R has no cutoff-frequency      (D) all three have cutoff-frequency

11. A fair coin is tossed 10 times. What is the probability that ONLY the first two tosses will yield heads?

- (A)  $\left(\frac{1}{2}\right)^2$       (B)  ${}^{10}C_2\left(\frac{1}{2}\right)^2$       (C)  $\left(\frac{1}{2}\right)^{10}$       (D)  ${}^{10}C_2\left(\frac{1}{2}\right)^{10}$

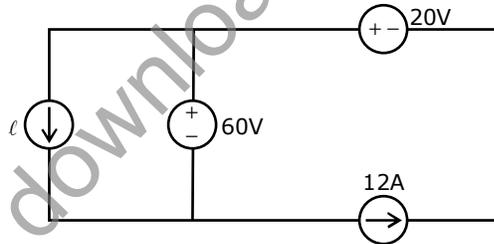
12. If the power spectral density of stationary random process is a sine-squared function of frequency, the shape of its autocorrelation is



13. If  $f(z) = c_0 + c_1z^{-1}$ , then  $\oint_{\text{unit circle}} \frac{1+f(z)}{z} dz$  is given by

- (A)  $2\pi c_1$       (B)  $2\pi(1+c_0)$       (C)  $2\pi j c_1$       (D)  $2\pi j(1+c_0)$

14. In the interconnection of ideal sources shown in the figure, it is known that the 60V source is absorbing power



Which of the following can be the value of the current source  $\ell$  ?

- (A) 10A      (B) 13A      (C) 15A      (D) 18A

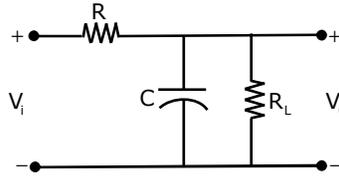
15. The ratio of the mobility to the diffusion coefficient in a semiconductor has the units

- (A)  $V^{-1}$       (B)  $\text{em} \cdot V^{-1}$       (C)  $V \cdot \text{cm}^{-1}$       (D)  $V \cdot s$

16. In a microprocessor, the service routine for a certain interrupt starts from a fixed location of memory which cannot be externally set, but the interrupt can be delayed or rejected. Such an interrupt is

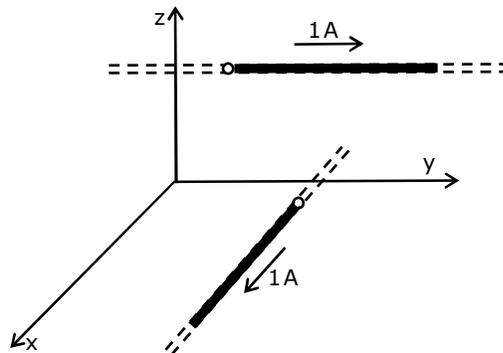
- (A) non-maskable and non-vectorred      (B) maskable and non-vectorred  
(C) non-maskable and vectored      (D) maskable and vectored

17. If the transfer function of the following network is  $\frac{V_o(s)}{V_i(s)} = \frac{1}{2 + s CR}$



The value of the load resistance  $R_L$  is

- (A)  $R/4$                       (B)  $R/2$                       (C)  $R$                       (D)  $2R$
18. Consider the system  $\frac{dx}{dt} = Ax + Bu$  with  $A = \begin{bmatrix} 1 & 0 \\ 0 & 1 \end{bmatrix}$  and  $B = \begin{bmatrix} p \\ q \end{bmatrix}$  where  $p$  and  $q$  are arbitrary real numbers. Which of the following statements about the controllability of the system is true?
- (A) The system is completely state controllable for any nonzero values of  $p$  and  $q$   
 (B) Only  $p=0$  and  $q=0$  result in controllability  
 (C) The system is uncontrollable for all values of  $p$  and  $q$   
 (D) We cannot conclude about controllability from the given data
19. For a message signal  $m(t) = \cos(2\pi f_m t)$  and carrier of frequency  $f_c$ , which of the following represents a single side band (SSB) signal?
- (A)  $\cos(2\pi f_m t) \cos(2\pi f_c t)$                       (B)  $\cos(2\pi f_c t)$   
 (C)  $\cos[2\pi(f_c + f_m)t]$                       (D)  $[1 + \cos(2\pi f_m t)] \cos(2\pi f_c t)$
20. Two infinitely long wires carrying current are as shown in the figure below. One wire is in the  $y-z$  plane and parallel to the  $y$ -axis. The other wire is in the  $x-y$  plane and parallel to the  $x$ -axis. Which components of the resulting magnetic field are non-zero at the origin?



- (A)  $x, y, z$  components                      (B)  $x, y$  components  
 (C)  $y, z$  components                      (D)  $x, z$  components

**Q. No. 21 – 56 Carry Two Marks Each**

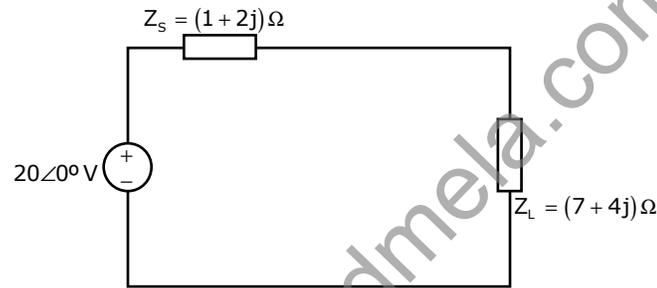
21. Consider two independent random variables X and Y with identical distributions. The variables X and Y take values 0, 1 and 2 with probabilities  $\frac{1}{2}$ ,  $\frac{1}{4}$  and  $\frac{1}{4}$  respectively. What is the conditional probability  $P(X + Y = 2 | X - Y = 0)$ ?
- (A) 0                      (B)  $\frac{1}{16}$                       (C)  $\frac{1}{6}$                       (D) 1
22. The Taylor series expansion of  $\frac{\sin x}{x - \pi}$  at  $x = \pi$  is given by
- (A)  $1 + \frac{(x - \pi)^2}{3!} + \dots$     (B)  $-1 - \frac{(x - \pi)^2}{3!} + \dots$     (C)  $1 - \frac{(x - \pi)^2}{3!} + \dots$     (D)  $-1 + \frac{(x - \pi)^2}{3!} + \dots$
23. If a vector field  $\vec{V}$  is related to another vector field  $\vec{A}$  through  $\vec{V} = \nabla \times \vec{A}$ , which of the following is true? Note: C and  $S_c$  refer to any closed contour and any surface whose boundary is C.
- (A)  $\oint_C \vec{V} \cdot d\vec{\ell} = \iint_{S_c} \vec{A} \cdot d\vec{S}$                       (B)  $\oint_C \vec{A} \cdot d\vec{\ell} = \iint_{S_c} \vec{V} \cdot d\vec{S}$   
 (C)  $\oint_C \nabla \times \vec{V} \cdot d\vec{\ell} = \iint_{S_c} \nabla \times \vec{A} \cdot d\vec{S}$                       (D)  $\oint_C \nabla \times \vec{A} \cdot d\vec{\ell} = \iint_{S_c} \vec{V} \cdot d\vec{S}$
24. Given that F(s) is the one-sided Laplace transform of f(t), the Laplace transform of  $\int_0^t f(\tau) d\tau$  is
- (A) sF(s) - f(0)    (B)  $\frac{1}{s}F(s)$     (C)  $\int_0^s F(\tau) d\tau$     (D)  $\frac{1}{s}[F(s) - f(0)]$
25. Match each differential equation in Group I to its family of solution curves from Group II.
- | <b>Group – I</b>                  | <b>Group – II</b>   |
|-----------------------------------|---------------------|
| P. $\frac{dy}{dx} = \frac{y}{x}$  | 1. Circles          |
| Q. $\frac{dy}{dx} = -\frac{y}{x}$ | 2. Straight lines   |
| R. $\frac{dy}{dx} = \frac{x}{y}$  | 3. Hyperbolas       |
| S. $\frac{dy}{dx} = -\frac{x}{y}$ |                     |
| (A) P-2,Q-3,R-3,S-1               | (B) P-1,Q-3,R-2,S-1 |
| (C) P-2,Q-1,R-3,S-3               | (D) P-3,Q-2,R-1,S-2 |

26. The eigen values of the following matrix are

$$\begin{bmatrix} -1 & 3 & 5 \\ -3 & -1 & 6 \\ 0 & 0 & 3 \end{bmatrix}$$

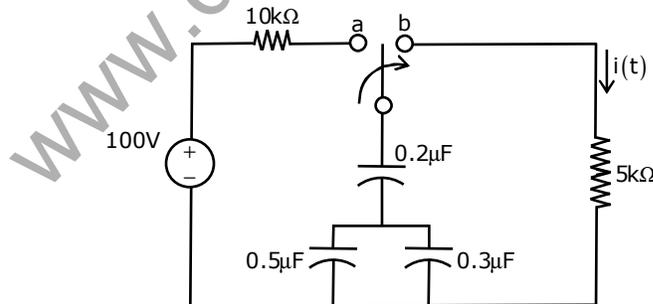
- (A)  $3, 3+5j, 6-j$  (B)  $-6+5j, 3+j, 3-j$   
 (C)  $3+j, 3-j, 5+j$  (D)  $3, -1+3j, -1-3j$

27. An AC source of RMS voltage 20V with internal impedance  $Z_s = (1+2j)\Omega$  feeds a load of impedance  $Z_L = (7+4j)\Omega$  in the figure below. The reactive power consumed by the load is



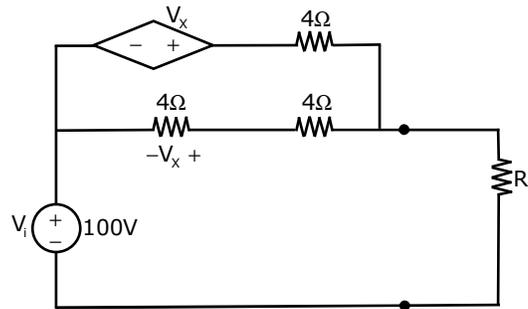
- (A) 8VAR (B) 16VAR (C) 28VAR (D) 32VAR

28. The switch in the circuit shown was on position a for a long time, and is moved to position b at time  $t=0$ . The current  $i(t)$  for  $t>0$  is given by



- (A)  $0.2e^{-125t}u(t)$  mA (B)  $20e^{-1250t}u(t)$  mA  
 (C)  $0.2e^{-1250t}u(t)$  mA (D)  $20e^{-1000t}u(t)$  mA

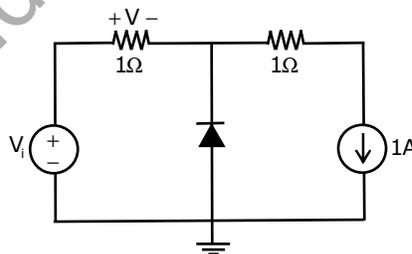
29. In the circuit shown, what value of  $R_L$  maximizes the power delivered to  $R_L$ ?



- (A)  $2.4\Omega$                       (B)  $\frac{8}{3}\Omega$                       (C)  $4\Omega$                       (D)  $6\Omega$
30. The time domain behavior of an RL circuit is represented by
- $$L \frac{di}{dt} + Ri = V_0 (1 + Be^{-Rt/L} \sin t) u(t).$$
- For an initial current of  $i(0) = \frac{V_0}{R}$ , the steady state value of the current is given by

- (A)  $i(t) \rightarrow \frac{V_0}{R}$                       (B)  $i(t) \rightarrow \frac{2V_0}{R}$   
 (C)  $i(t) \rightarrow \frac{V_0}{R} (1 + B)$                       (D)  $i(t) \rightarrow \frac{2V_0}{R} (1 + B)$

31. In the circuit below, the diode is ideal. The voltage  $V$  is given by

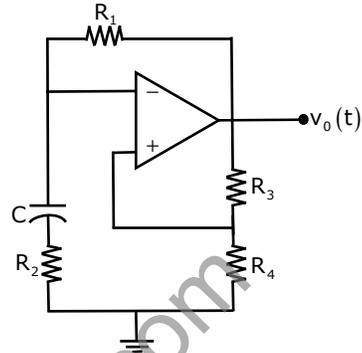


- (A)  $\min(V_i, 1)$                       (B)  $\max(V_i, 1)$                       (C)  $\min(-V_i, 1)$                       (D)  $\max(-V_i, 1)$
32. Consider the following two statements about the internal conditions in an n-channel MOSFET operating in the active region
- S1: The inversion charge decreases from source to drain  
 S2: The channel potential increases from source to drain
- Which of the following is correct?
- (A) Only S2 is true

- (B) Both S1 and S2 are false
- (C) Both S1 and S2 are true, but S2 is not a reason for S1
- (D) Both S1 and S2 are true, and S2 is a reason for S1

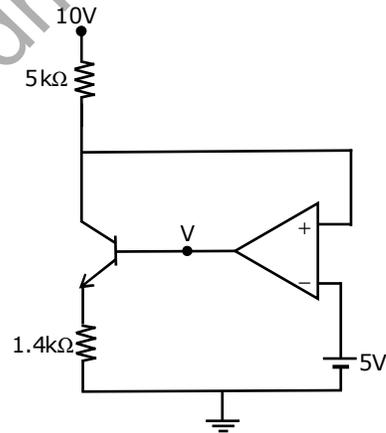
33. In the following astable multivibrator circuit, which properties of  $v_o(t)$  depend on  $R_2$ ?

- (A) Only the frequency
- (B) Only the amplitude
- (C) Both the amplitude and the frequency
- (D) Neither the amplitude nor the frequency



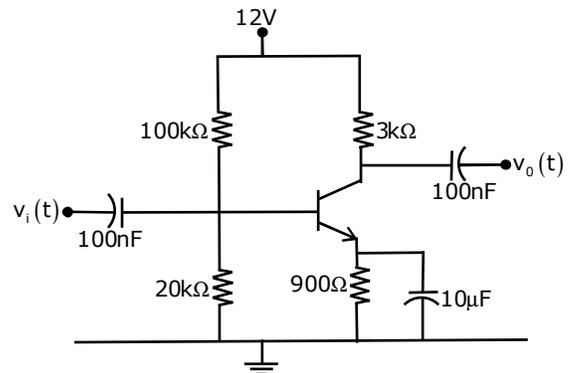
34. In the circuit shown below, the op-amp is ideal, the transistor has  $V_{BE} = 0.6V$  and  $\beta = 150$ . Decide whether the feedback in the circuit is positive or negative and determine the voltage  $V$  at the output of the op-amp

- (A) Positive feedback,  $V=10V$
- (B) Positive feedback,  $V=0V$
- (C) Negative feedback,  $V=5V$
- (D) Negative feedback,  $V=2V$



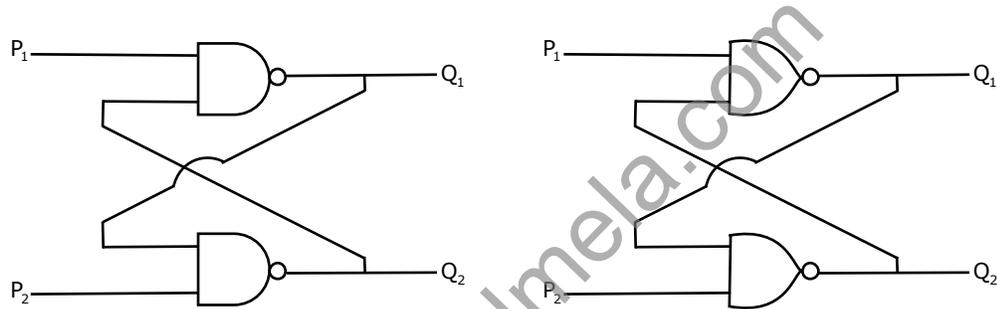
35. A small signal source  $v_i(t) = A \cos 20t + B \sin 10^6 t$  is applied to a transistor amplifier as shown below. The transistor has  $\beta = 150$  and  $h_{ie} = 3k\Omega$ . Which expression best approximates  $V_o(t)$

- (A)  $v_o(t) = -1500(A \cos 20t + B \sin 10^6 t)$
- (B)  $v_o(t) = -150(A \cos 20t + B \sin 10^6 t)$
- (C)  $v_o(t) = -1500B \sin 10^6 t$
- (D)  $v_o(t) = -150B \sin 10^6 t$

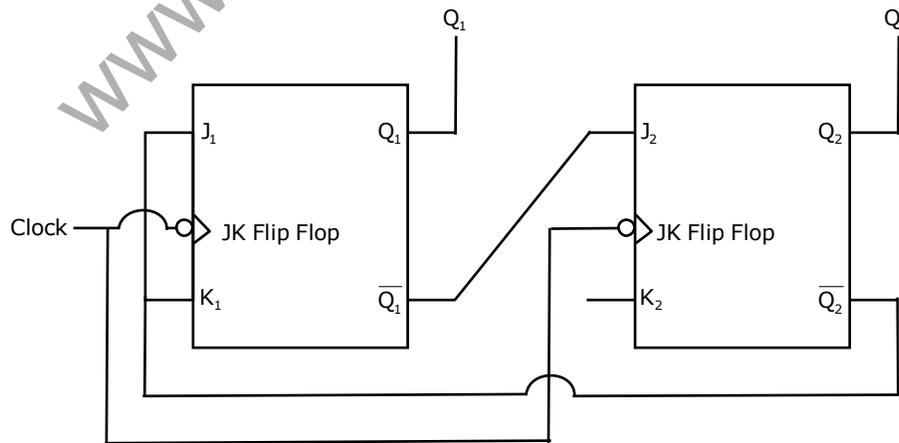


36. If  $X = 1$  in the logic equation  $\left[ X + Z \left\{ \bar{Y} + (\bar{Z} + X\bar{Y}) \right\} \right] \left\{ \bar{X} + \bar{Z}(X + Y) \right\} = 1$ , then  
 (A)  $Y=Z$                       (B)  $Y = \bar{Z}$                       (C)  $Z=1$                       (D)  $Z=0$
37. What are the minimum number of 2 to 1 multiplexers required to generate a 2 input AND gate and a 2 input Ex-OR gate?  
 (A) 1 and 2                      (B) 1 and 3                      (C) 1 and 1                      (D) 2 and 2

38. Refer to the NAND and NOR latches shown in the figure. The inputs  $(P_1, P_2)$  for both the latches are first made  $(0, 1)$  and then, after a few seconds, made  $(1, 1)$ . The corresponding stable outputs  $(Q_1, Q_2)$  are



- (A) NAND: first  $(0, 1)$  then  $(0, 1)$  NOR: first  $(1, 0)$  then  $(0, 0)$   
 (B) NAND: first  $(1, 0)$  then  $(1, 0)$  NOR: first  $(1, 0)$  then  $(1, 0)$   
 (C) NAND: first  $(1, 0)$  then  $(1, 0)$  NOR: first  $(1, 0)$  then  $(0, 0)$   
 (D) NAND: first  $(1, 0)$  then  $(1, 1)$  NOR: first  $(0, 1)$  then  $(0, 1)$
39. What are the counting stages  $(Q_1, Q_2)$  for the counter shown in the figure below?



- (A) 11,10,00,11,10,....                      (B) 01,10,11,00,01,....  
 (C) 00,11,01,10,00,....                      (D) 01,10,00,01,10,....

40. A system with transfer function  $H(z)$  has impulse response  $h(\cdot)$  defined as  $h(2)=1$ ,  $h(3)=-1$  and  $h(k)=0$  otherwise. Consider the following statements

S1 :  $H(z)$  is a low pass filter  
 S2 :  $H(z)$  is a FIR filter

Which of the following is correct?

- (A) Only S2 is true  
 (B) Both S1 and S2 are false  
 (C) Both S1 and S2 are true, and S2 is a reason for S1  
 (D) Both S1 and S2 are true, but S2 is not a reason for S1
41. Consider a system whose input  $x$  and output  $y$  are related by the equation

$$y(t) = \int_{-\infty}^{\infty} x(t - \tau)h(2\tau) d\tau$$

Where  $h(t)$  is shown in the graph

Which of the following four properties are possessed by the system?

BIBO: Bounded input gives a bounded output

Causal: The system is causal

LP: The system is low pass

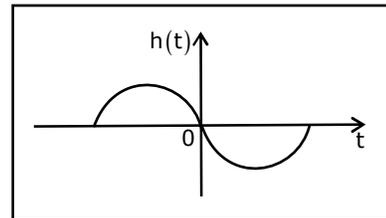
LTI: The system is linear and time invariant

(A) Causal, LP

(B) BIBO, LTI

(C) BIBO, Causal, LTI

(D) LP, LTI



42. The 4 point Discrete Fourier Transform (DFT) of a discrete time sequence  $\{1, 0, 2, 3\}$  is

(A)  $[0, -2 + 2j, 2, -2 - 2j]$

(B)  $[2, 2 + 2j, 6, 2 - 2j]$

(C)  $[6, 1 - 3j, 2, 1 + 3j]$

(D)  $[6, -1 + 3j, 0, -1 - 3j]$

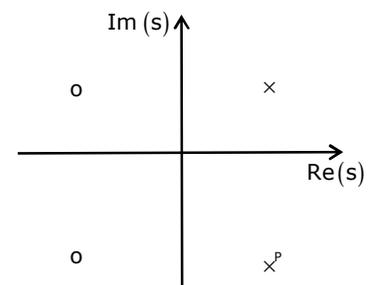
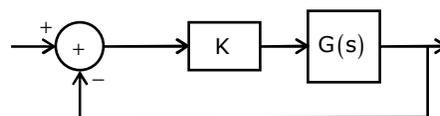
43. The feedback configuration and the pole-zero locations of  $G(s) = \frac{s^2 - 2s + 2}{s^2 + 2s + 2}$  are shown below. The root locus for negative values of  $k$ , i.e. for  $-\infty < k < 0$ , has breakaway/break in points and angle of departure at pole  $P$  (with respect to the positive real axis) equal to

(A)  $\pm\sqrt{2}$  and  $0^\circ$  **Error! Not a valid link.**

(B)  $\pm\sqrt{2}$  and  $45^\circ$

(C)  $\pm\sqrt{3}$  and  $0^\circ$

(D)  $\pm\sqrt{3}$  and  $45^\circ$





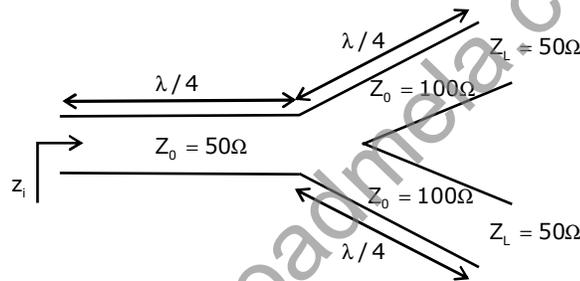
49. A magnetic field in air is measured to be

$$\vec{B} = B_0 \left( \frac{x}{x^2 + y^2} \hat{y} - \frac{y}{x^2 + y^2} \hat{x} \right)$$

What current distribution leads to this field? [Hint: The algebra is trivial in cylindrical coordinates.]

- (A)  $\vec{J} = \frac{B_0 \hat{z}}{\mu_0} \left( \frac{1}{x^2 + y^2} \right), r \neq 0$                       (B)  $\vec{J} = \frac{B_0 \hat{z}}{\mu_0} \left( \frac{2}{x^2 + y^2} \right), r \neq 0$   
 (C)  $\vec{J} = 0, r \neq 0$     (D)  $\vec{J} = \frac{B_0 \hat{z}}{\mu_0} \left( \frac{1}{x^2 + y^2} \right), r \neq 0$

50. A transmission line terminates in two branches, each of length  $\lambda/4$ , as shown. The branches are terminated by  $50\Omega$  loads. The lines are lossless and have the characteristic impedances shown. Determine the impedance  $Z_1$  as seen by the source



- (A)  $200\Omega$                       (B)  $100\Omega$                       (C)  $50\Omega$                       (D)  $25\Omega$

**Common Data Questions: 51 & 52**

Consider a silicon p-n junction at room temperature having the following parameters:

- Doping on the n-side =  $1 \times 10^{17} \text{cm}^{-3}$
- Depletion width on the n-side =  $0.1\mu\text{m}$
- Depletion width on the p-side =  $1.0\mu\text{m}$
- Intrinsic carrier concentration =  $1.4 \times 10^{14} \text{F. cm}^{-1}$
- Thermal voltage =  $26\text{mV}$
- Permittivity of free space =  $8.85 \times 10^{-14} \text{F. cm}^{-1}$
- Dielectric constant of silicon = 12

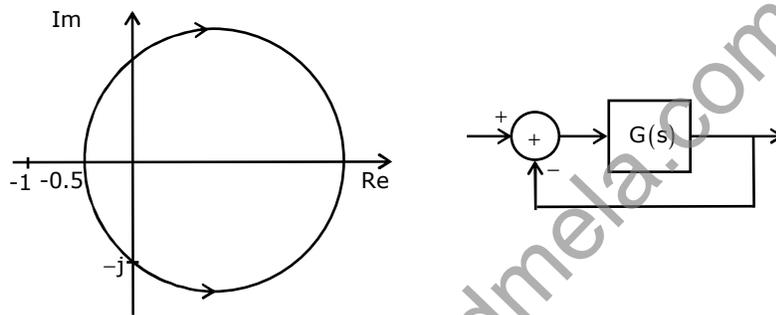
51. The built in potential of the junction

- (A) is  $0.70\text{V}$   
 (B) is  $0.76\text{V}$   
 (C) is  $0.82\text{V}$   
 (D) cannot be estimated from the data given

52. The peak electric field in the device is  
 (A)  $0.15 \text{ MV.cm}^{-1}$ , directed from p-region to n-region  
 (B)  $0.15 \text{ MV.cm}^{-1}$ , directed from n-region to p-region  
 (C)  $1.80 \text{ MV.cm}^{-1}$ , directed from p-region to n-region  
 (D)  $1.80 \text{ MV.cm}^{-1}$ , directed from n-region to p-region

**Common Data Questions: 53 & 54**

The Nyquist plot of a stable transfer function  $G(s)$  is shown in the figure. We are interested in the stability of the closed loop system in the feedback configuration shown.



53. Which of the following statements is true?  
 (A)  $G(s)$  is an all-pass filter  
 (B)  $G(s)$  has a zero in the right-half plane  
 (C)  $G(s)$  is the impedance of a passive network  
 (D)  $G(s)$  is marginally stable
54. The gain and phase margins of  $G(s)$  for closed loop stability are  
 (A) 6dB and  $180^\circ$     (B) 3dB and  $180^\circ$     (C) 6dB and  $90^\circ$     (D) 3dB and  $90^\circ$

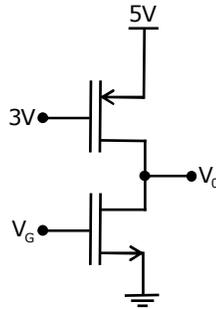
**Common Data Questions: 55 & 56**

- The amplitude of a **random** signal is uniformly distributed between -5V and 5V
55. If the signal to quantization noise ratio required in uniformly quantizing the signal is 43.5dB, the step size of the quantization is approximately  
 (A) 0.0333V    (B) 0.05V    (C) 0.0667V    (D) 0.10V
56. If the positive values of the signal are uniformly quantized with a step size of 0.05V, and the negative values are uniformly quantized with a step size of 0.1V, the resulting signal to quantization noise ratio is approximately  
 (A) 46dB    (B) 43.8dB    (C) 42dB    (D) 40dB

**Linked Answer Questions: Q.57 to Q.60 Carry Two Marks Each**

**Statement for Linked Answer Questions: 57 & 58**

Consider the CMOS circuit shown, where the gate voltage  $V_G$  of the n-MOSFET is increased from zero, while the gate voltage of the p-MOSFET is kept constant at 3 V. Assume that, for both transistors, the magnitude of the threshold voltage is 1 V and the product of the transconductance parameter and the  $(W/L)$  ratio, i.e. the quantity  $\mu C_{ox} (W/L)$ , is  $1\text{mA} \cdot \text{V}^{-2}$ .



57. For small increase in  $V_G$  beyond 1V, which of the following gives the correct description of the region of operation of each MOSFET?
- (A) Both the MOSFETs are in saturation region
  - (B) Both the MOSFETs are in triode region
  - (C) n-MOSFET is in triode and p-MOSFET is in saturation region
  - (D) n-MOSFET is in saturation and p-MOSFET is in triode region
58. Estimate the output voltage  $V_0$  for  $V_G=1.5\text{V}$ . [Hint: Use the appropriate current voltage equation for each MOSFET, based on the answer to Q.57]
- (A)  $4 - \frac{1}{\sqrt{2}} \text{V}$       (B)  $4 + \frac{1}{\sqrt{2}} \text{V}$       (C)  $4 - \frac{\sqrt{3}}{2} \text{V}$       (D)  $4 + \frac{\sqrt{3}}{2} \text{V}$

**Statement for Linked Answer Questions: 59 & 60**

Two products are sold from a vending machine, which has two push buttons  $P_1$  and  $P_2$ . When a button is pressed, the price of the corresponding product is displayed in a 7-segment display.

If no buttons are pressed, '0' is displayed, signifying 'Rs. 0'.

If only  $P_1$  is pressed, '2' is displayed, signifying 'Rs. 2'.

If only  $P_2$  is pressed, '5' is displayed, signifying 'Rs. 5'.

If both  $P_1$  and  $P_2$  are pressed, 'E' is displayed, signifying 'Error'.

The names of the segments in the 7-segment display, and the glow of the display for '0', '2', '5' and 'E', are shown below





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